

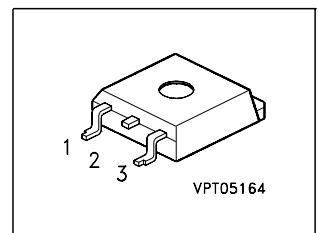


Features

- Logic Level Input
- Input Protection (ESD)
- Thermal shutdown with latch
- Overload protection
- Short circuit protection
- Overvoltage protection
- Current limitation
- Status feedback with external input resistor
- Analog driving possible
- AEC qualified
- Green product (RoHS compliant)

Product Summary

Drain source voltage	V_{DS}	60	V
On-state resistance	$R_{DS(on)}$	100	m Ω
Current limit	$I_{D(lim)}$	7	A
Nominal load current	$I_{D(ISO)}$	3.5	A
Clamping energy	E_{AS}	1000	mJ

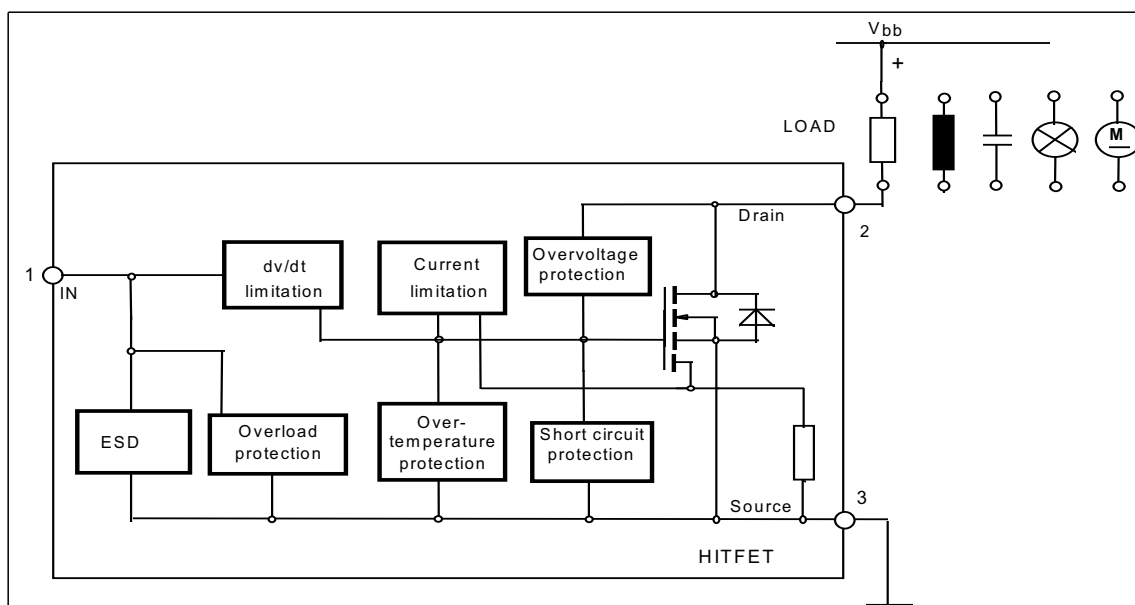


Application

- All kinds of resistive, inductive and capacitive loads in switching or linear applications
- μ C compatible power switch for 12 V and 24 V DC applications
- Replaces electromechanical relays and discrete circuits

General Description

N channel vertical power FET in Smart SIPMOS[®] chip on chip technology. Providing embedded protection functions.



Maximum Ratings at $T_j = 25\text{ °C}$ unless otherwise specified

Parameter	Symbol	Value	Unit
Drain source voltage	V_{DS}	60	V
Drain source voltage for short circuit protection	$V_{DS(SC)}$	32	
Continuous input current ¹⁾ -0.2V $\leq V_{IN} \leq$ 10V $V_{IN} < -0.2V$ or $V_{IN} > 10V$	I_{IN}	no limit $ I_{IN} \leq 2$	mA
Operating temperature	T_j	- 40 ... +150	°C
Storage temperature	T_{stg}	- 55 ... +150	
Power dissipation $T_C = 25\text{ °C}$	P_{tot}	50	W
Unclamped single pulse inductive energy $I_{D(ISO)} = 3.5\text{ A}$	E_{AS}	1000	mJ
Electrostatic discharge voltage (Human Body Model) according to MIL STD 883D, method 3015.7 and EOS/ESD assn. standard S5.1 - 1993	V_{ESD}	3000	V
Load dump protection $V_{LoadDump}^{2)} = V_A + V_S$ $V_{IN} = \text{low or high}; V_A = 13.5\text{ V}$ $t_d = 400\text{ ms}, R_l = 2\ \Omega, I_D = 0,5 * 3.5A$	V_{LD}	75	
$t_d = 400\text{ ms}, R_l = 2\ \Omega, I_D = 3.5A$		70	

Thermal resistance

junction - case:	R_{thJC}	2.5	K/W
junction - ambient:	R_{thJA}	75	
SMD version, device on PCB: ³⁾	R_{thJA}	45	

¹⁾In case of thermal shutdown a minimum sensor holding current of 500 μA has to be guaranteed (see also page 3).

²⁾ $V_{Loaddump}$ is setup without the DUT connected to the generator per ISO 7637-1 and DIN 40839

³⁾ Device on 50mm*50mm*1.5mm epoxy PCB FR4 with 6cm² (one layer, 70 μm thick) copper area for Drain connection. PCB mounted vertical without blown air.

Electrical Characteristics

Parameter at $T_j=25^\circ\text{C}$, unless otherwise specified	Symbol	Values			Unit
		min.	typ.	max.	
Characteristics					
Drain source clamp voltage $T_j = -40 \dots +150^\circ\text{C}$, $I_D = 10 \text{ mA}$	$V_{DS(AZ)}$	60	-	73	V
Off state drain current $V_{DS} = 32 \text{ V}$, $T_j = -40\dots+150^\circ\text{C}$, $V_{IN} = 0 \text{ V}$	I_{DSS}	-	-	5	μA
Input threshold voltage $I_D = 0.7 \text{ mA}$	$V_{IN(th)}$	1.3	1.7	2.2	V
Input current - normal operation, $I_D < I_{D(lim)}$: $V_{IN} = 10 \text{ V}$	$I_{IN(1)}$	-	30	60	μA
Input current - current limitation mode, $I_D = I_{D(lim)}$: $V_{IN} = 10 \text{ V}$	$I_{IN(2)}$	-	120	300	
Input current - after thermal shutdown, $I_D = 0 \text{ A}$: $V_{IN} = 10 \text{ V}$	$I_{IN(3)}$	800	2200	4000	
Input holding current after thermal shutdown ¹⁾ $T_j = 25^\circ\text{C}$ $T_j = 150^\circ\text{C}$	$I_{IN(H)}$	500 300	- -	- -	
On-state resistance $V_{IN} = 5 \text{ V}$, $I_D = 3.5 \text{ A}$, $T_j = 25^\circ\text{C}$ $V_{IN} = 5 \text{ V}$, $I_D = 3.5 \text{ A}$, $T_j = 150^\circ\text{C}$	$R_{DS(on)}$	- -	90 180	120 240	$\text{m}\Omega$
On-state resistance $V_{IN} = 10 \text{ V}$, $I_D = 3.5 \text{ A}$, $T_j = 25^\circ\text{C}$ $V_{IN} = 10 \text{ V}$, $I_D = 3.5 \text{ A}$, $T_j = 150^\circ\text{C}$	$R_{DS(on)}$	- -	80 160	100 200	
Nominal load current (ISO 10483) $V_{IN} = 10 \text{ V}$, $V_{DS} = 0.5 \text{ V}$, $T_C = 85^\circ\text{C}$	$I_{D(ISO)}$	3.5	-	-	A

¹If the input current is limited by external components, low drain currents can flow and heat the device. Auto restart behaviour can occur.

Electrical Characteristics

Parameter at $T_j=25^\circ\text{C}$, unless otherwise specified	Symbol	Values			Unit
		min.	typ.	max.	

Characteristics

Initial peak short circuit current limit $V_{IN} = 10\text{ V}$, $V_{DS} = 12\text{ V}$	$I_{D(SCp)}$	-	25	-	A
Current limit ¹⁾ $V_{IN} = 10\text{ V}$, $V_{DS} = 12\text{ V}$, $t_m = 350\ \mu\text{s}$, $T_j = -40\dots+150\ ^\circ\text{C}$	$I_{D(lim)}$	7	10	15	

Dynamic Characteristics

Turn-on time V_{IN} to 90% I_D : $R_L = 4.7\ \Omega$, $V_{IN} = 0$ to 10 V , $V_{bb} = 12\text{ V}$	t_{on}	-	40	70	μs
Turn-off time V_{IN} to 10% I_D : $R_L = 4.7\ \Omega$, $V_{IN} = 10$ to 0 V , $V_{bb} = 12\text{ V}$	t_{off}	-	70	150	
Slew rate on 70 to 50% V_{bb} : $R_L = 4.7\ \Omega$, $V_{IN} = 0$ to 10 V , $V_{bb} = 12\text{ V}$	$-dV_{DS}/dt_{on}$	-	1	3	$\text{V}/\mu\text{s}$
Slew rate off 50 to 70% V_{bb} : $R_L = 4.7\ \Omega$, $V_{IN} = 10$ to 0 V , $V_{bb} = 12\text{ V}$	dV_{DS}/dt_{off}	-	1	3	

Protection Functions ²⁾

Thermal overload trip temperature	T_{it}	150	165	-	$^\circ\text{C}$
Unclamped single pulse inductive energy $I_D = 3.5\text{ A}$, $T_j = 25\ ^\circ\text{C}$, $V_{bb} = 32\text{ V}$ $I_D = 3.5\text{ A}$, $T_j = 150\ ^\circ\text{C}$, $V_{bb} = 32\text{ V}$	E_{AS}	1000 225	-- --	-- --	mJ

Inverse Diode

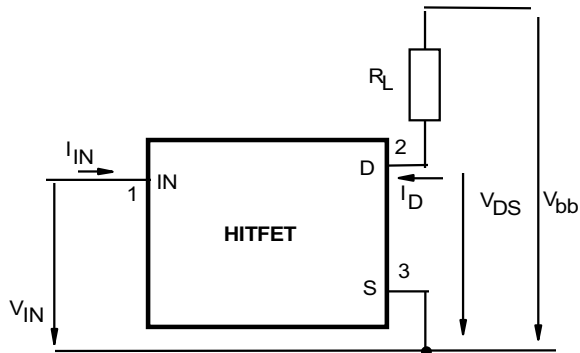
Inverse diode forward voltage $I_F = 5*3.5\text{A}$, $t_m = 300\ \mu\text{s}$, $V_{IN} = 0\text{ V}$	V_{SD}	-	1	-	V
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¹⁾Device switched on into existing short circuit (see diagram Determination of $I_{D(lim)}$). If the device is in on condition and a short circuit occurs, these values might be exceeded for max. 50 μs .

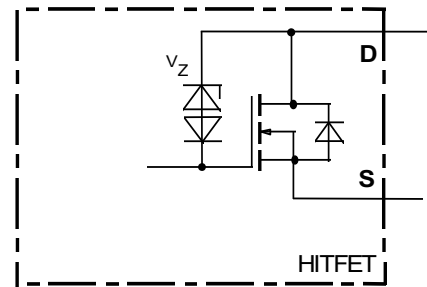
²⁾Integrated protection functions are designed to prevent IC destruction under fault conditions described in the data sheet. Fault conditions are considered as "outside" normal operating range. Protection functions are not designed for continuous repetitive operation.

Block Diagramm

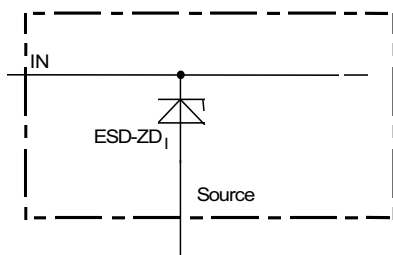
Terms



Inductive and overvoltage output clamp

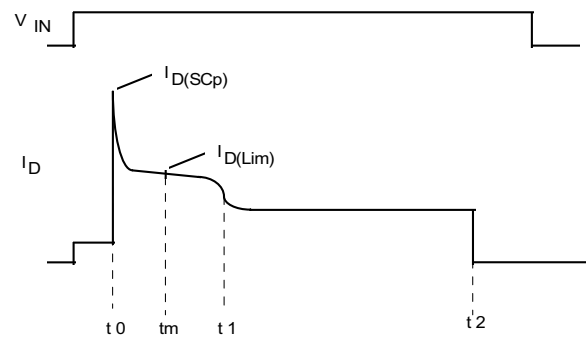


Input circuit (ESD protection)



ESD zener diodes are not designed for DC current $> 2 \text{ mA}$ @ $V_{IN} > 10 \text{ V}$.

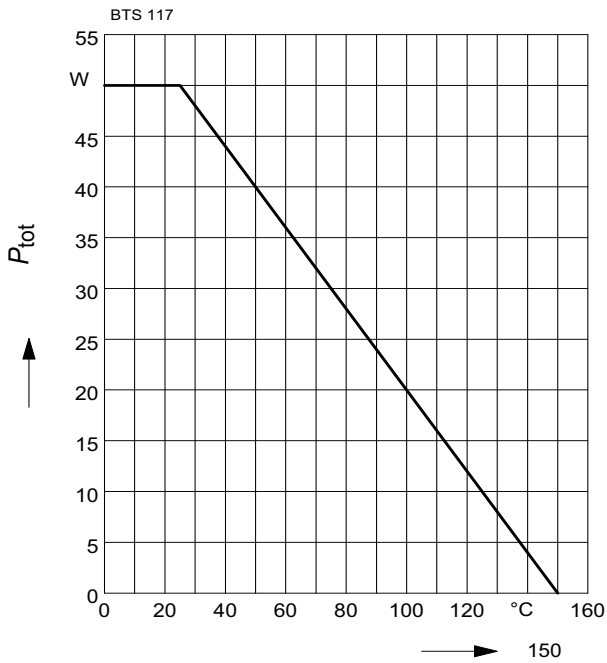
Short circuit behaviour



- t_0 : Turn on into a short circuit
- t_m : Measurementpoint for $I_{D(Lim)}$
- t_1 : Activation of the fast temperature sensor and regulation of the drain current to a level where the junction temperature remains constant.
- t_2 : Thermal shutdown caused by the second temperature sensor, achieved by an integrating measurement.

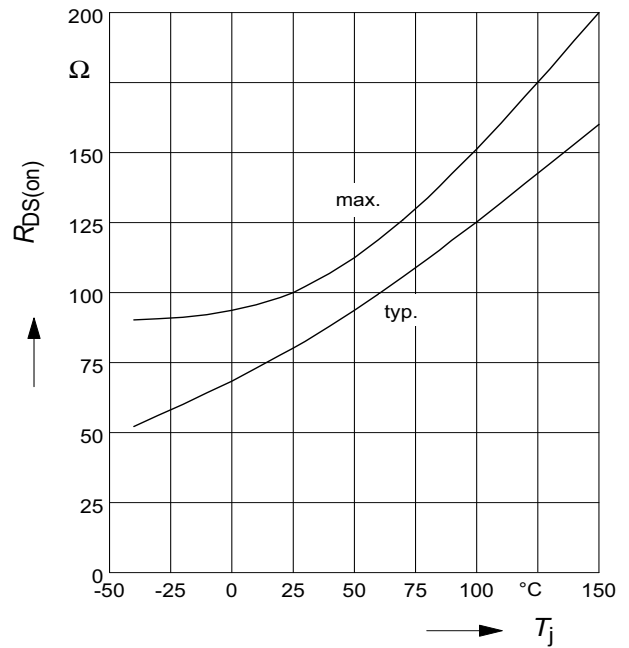
Maximum allowable power dissipation

$P_{tot} = f(T_c)$



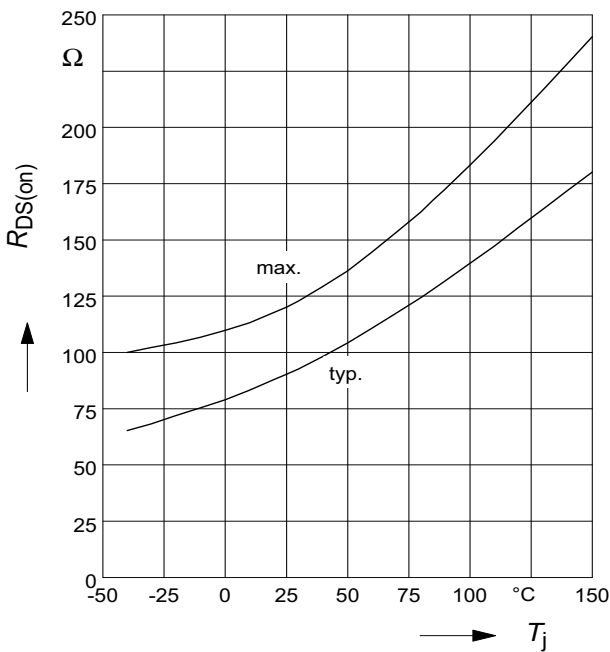
On-state resistance

$R_{ON} = f(T_j); I_D=3.5A; V_{IN}=10V$



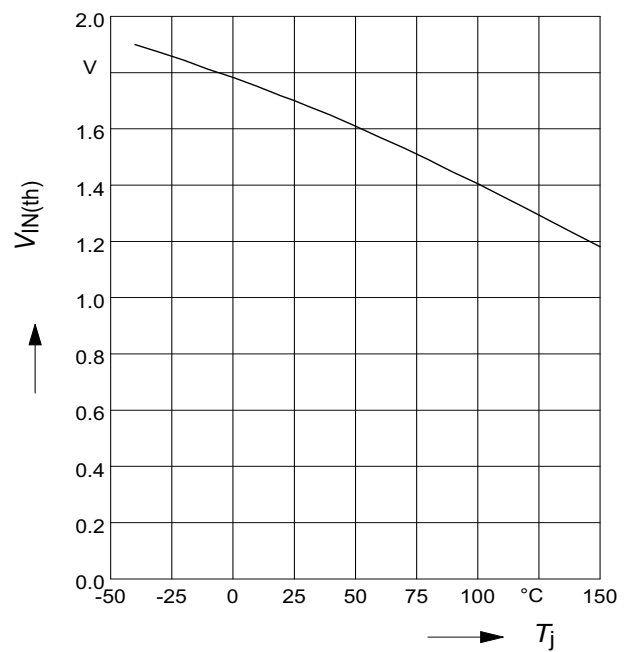
On-state resistance

$R_{ON} = f(T_j); I_D= 3.5A; V_{IN}=5V$



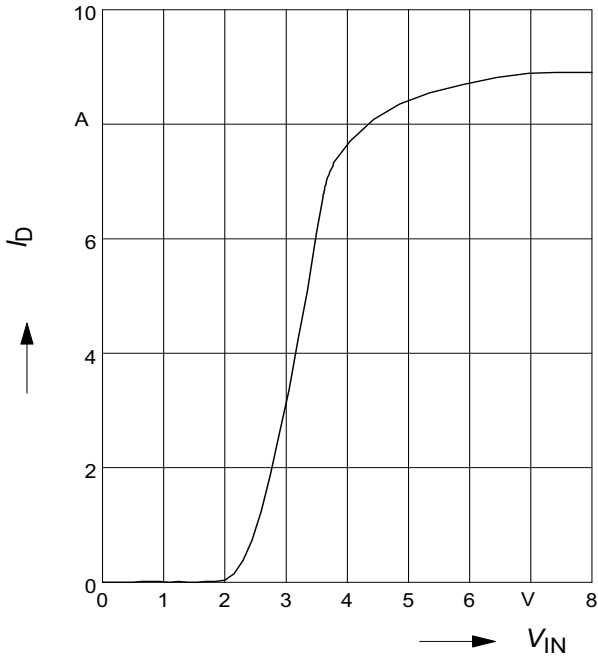
Typ. input threshold voltage

$V_{IN(th)} = f(T_j); I_D=0.7mA; V_{DS}=12V$



Typ. transfer characteristics

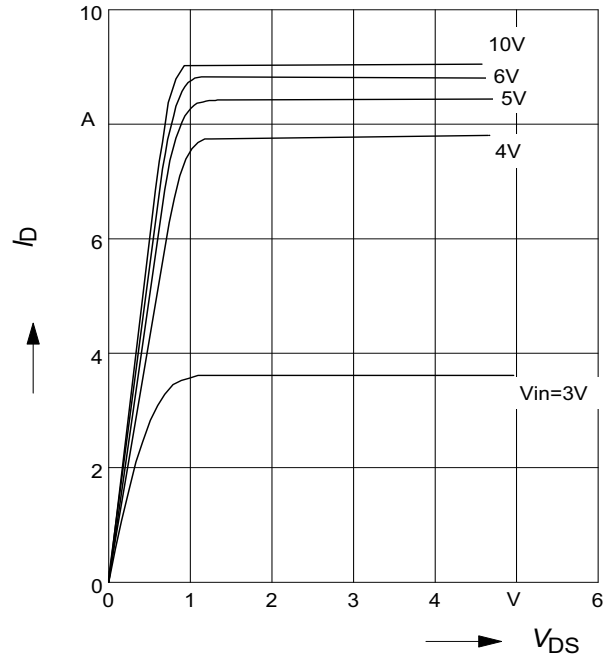
$I_D = f(V_{IN}); V_{DS}=12V; T_j=25^\circ C$



Typ. output characteristic

$I_D = f(V_{DS}); T_j=25^\circ C$

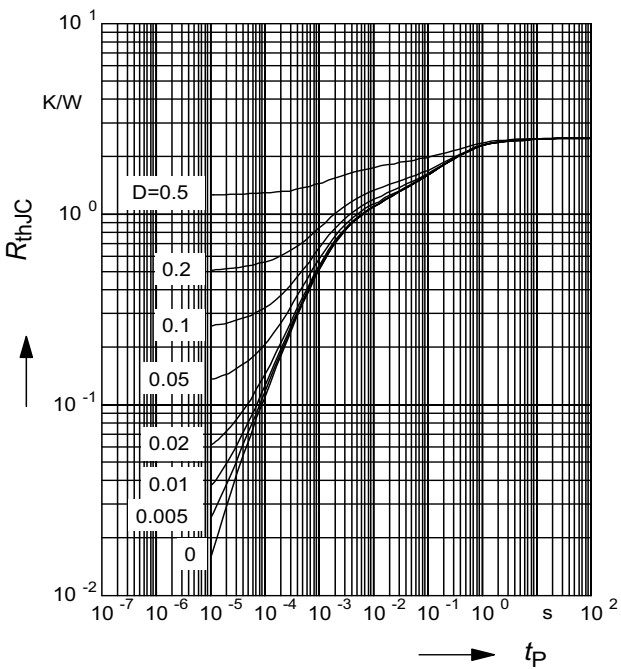
Parameter: V_{IN}



Transient thermal impedance

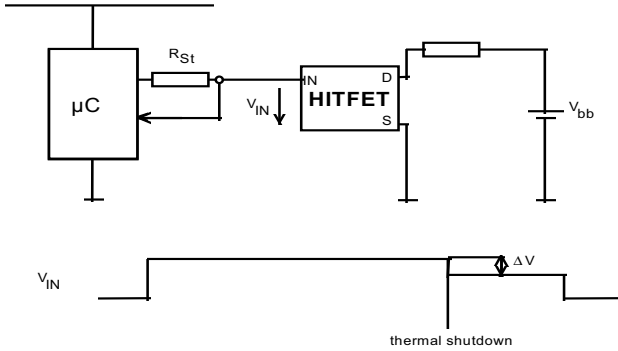
$Z_{thJC} = f(t_p)$

parameter : $D = t_p/T$



Application examples:

Status signal of thermal shutdown by monitoring input current



$$\Delta V = R_{ST} * I_{N(3)}$$

1 Package Outlines

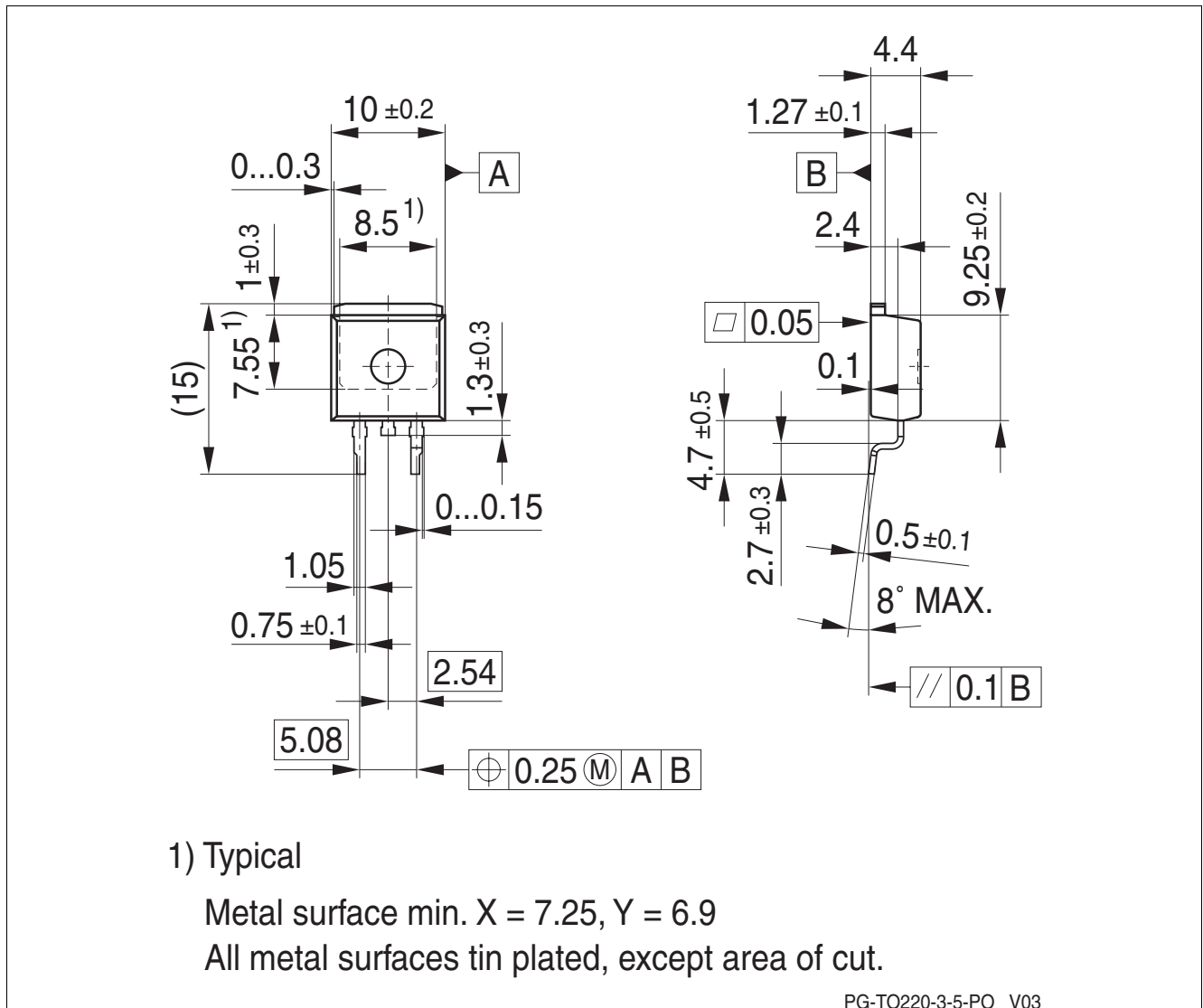


Figure 1 PG-TO220-3-5 (Plastic Dual Small Outline Package) (RoHS-Compliant)

To meet the world-wide customer requirements for environmentally friendly products and to be compliant with government regulations the device is available as a green product. Green products are RoHS-Compliant (i.e Pb-free finish on leads and suitable for Pb-free soldering according to IPC/JEDEC J-STD-020).

Please specify the package needed (e.g. green package) when placing an order

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Dimensions in mm

2 Revision History

Version	Date	Changes
Rev. 1.3	2008-12-10	released automotive green and robust version Package drawing updated
Rev. 1.2	2008-08-11	Package information updated, removed through hole versions
Rev. 1.1	2008-02-22	Package parameter (humidity and climatic) removed in Maximum ratings AEC icon and RoHS icon added Green product and AEC qualified added to the feature list added Protection footnote on Page 4 and changed front page general description Package information updated to green Green explanation added
Rev. 1.0	2000-05-19	released production version

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